Diode Semiconductor Device - Page 1 of 1



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Inclo	sure Material:
Meta	I
Over	all Length:
0.375	5 inches
Term	inal Length:
1.000) inches
Over	all Diameter:
0.220) inches
Mour	nting Method:
Term	inal
Featu	ures Provided:
Herm	netically sealed case
Semi	iconductor Material:
Silico	n
Volta	ge Rating In Volts Per Characteristic:
200.0) reverse voltage, peak
Curre	ent Rating Per Characteristic:
55.00) amperes forward current, average absolute
Maxi	mum Operating Tempurature Per Measurement Point:
150.0) degrees celsius ambient air
Term	inal Type And Quantity:
2 unii	nsulated wire lead
Spec	ification Data:
8013	1-release3465 professional/industrial association specification
Shelf	f Life:
N/a	
Unit	Of Measure:
Demi	ilitarization:
No	
Fiig:	
A110	a0